Current Mode Memristor Crossbars for Neuromorphic Computing

Neuro-Inspired Computational Elements Workshop, 2019

Cory Merkel, Ph.D.

Assistant Professor

Department of Computer Engineering

Rochester Institute of Technology





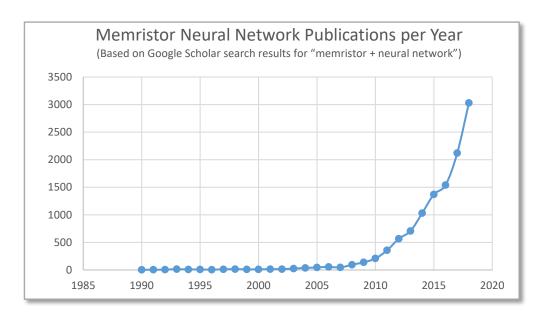
- Background and Motivation
- Current-Mode Crossbars
- MNIST Experiments
- Conclusions and Future Work



- Background and Motivation
- Current-Mode Crossbars
- MNIST Experiments
- Conclusions and Future Work

Motivation





 Previous work proposes voltage-driven crossbars for neural network weight matrices^{2,3}

¹C. Merkel et al., "Neuromemristive systems: Boosing efficiency through brain-inspired computing," IEEE Computer, October 2016.

²G. Indiveri et al., "Integration of nanoscale memristor synapses in neuromorphic computingarchitectures," Nanotechnology, 2013.

³G. W. Burr et al., "Neuromorphic computing using non-volatilememory," Advances in Physics: X, vol. 2, no. 1, pp. 89–124, 2017.

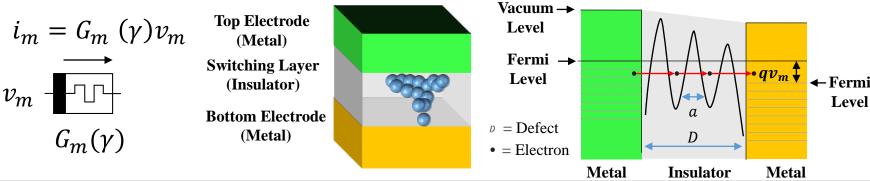
Motivation



- Voltage-mode neurons driving memristor crossbars suffer from a few drawbacks:
 - Large memristor conductances → Neuron output degradation
 - IR drop over long-distance communication pathways
- Some solutions: 1T1R, spiking networks
- Current-mode designs offer
 - Better input/output swing, reduced loading issues
 - Low voltage operation and higher bandwidth
 - Nice design techniques (e.g. translinear principle)

Can we operate a memristor crossbar in current mode (current in, current out) for neuromorphic computing?

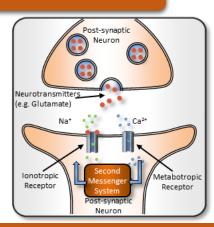
- Memristor = "Memory + Resistor"
 - -2-Terminal thin-film device with state-dependent Ohm's Law (Chua, 2011)



Similar to Biological Synapses

Facilitate:

- 1.) Computation
- 2.) Memory
- 3.) Learning



		1	vietai	Insulator	Metal
		Memristors			
Metric	Flash	PCM	STT-RAM	RRAM	Targets
Dynamic Range	-	>1000	2	1000	>4
Number of States	8-16	100	4	100	20-100
Retention	Several years at room temp.				Years
Energy (pJ/bit)	>100	2-25	0.1-2.5	0.1-3	0.01
Endurance (cycles)	104	10 ⁹	10 ¹⁵	10 ¹²	10 ⁹

Table compiled from (Yang et al., 2013; Kuzum et al., 2013; Devised et al., 2013; Ishigaki et al., 2



- Background and Motivation
- Current-Mode Crossbars
- MNIST Experiments
- Conclusions and Future Work

Voltage-Mode Memristor Xbar 🕻 🕃

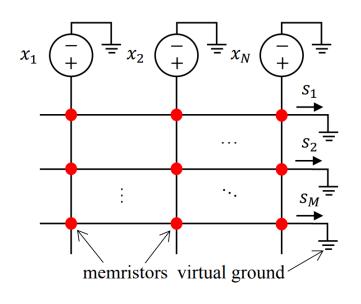
brain·lab

 Matrix-vector multiplication implemented by xbar as

$$s = Wx$$

 Each weight is defined by a single memristor conductance

$$w_{ij} = G_{ij}/G_{max}$$



Weight range

$$g \le w_{ij} \le 1$$

where $g \equiv G_{min}/G_{max}$

Current-Mode Memristor Xbar &

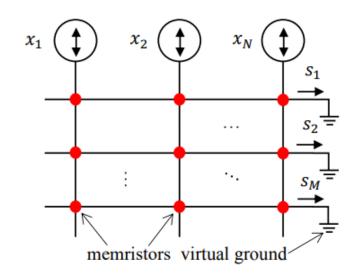


brain·lab

 The weight definition becomes:

$$w_{ij} = \frac{G_{ij}}{\sum_{k=1}^{M} G_{kj}}$$

 The maximum driving current should be



$$I_{max} < V_{th} \sum_{i} G_{ij}$$

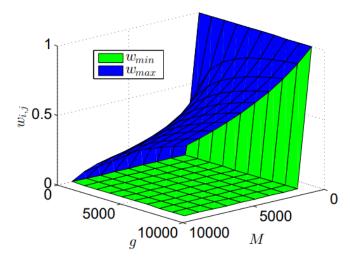
to avoid read disturb

Weight Range



Weight range depends on the fanout:

$$\frac{1}{(M-1)g+1} \le w_{ij} \le \frac{g}{M-1+g}$$



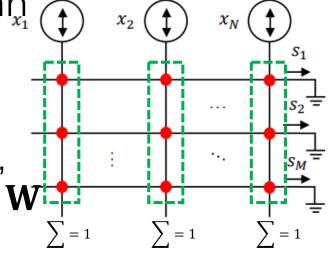
- ullet Range approaches [0,1] for large g
- May need to split into multiple crossbars for very large M

Weight Distribution



• Constraint: Weights in a column must sum to 1

 Given a target weight matrix W, find closest constrained matrix W



minimize
$$\sum_{i=1}^{M} \sum_{j=1}^{N} (w_{ij} - \overline{w}_{ij})^{2}$$
s.t.
$$\sum_{i} w_{ij} = 1 \ \forall j = 1, 2, ..., N$$

$$w_{min} \leq w_{ij} \leq w_{max}$$

$$w_{ij} = \frac{1}{M} \left(1 - \sum_{k=1}^{M} \overline{w}_{kj} \right) + \overline{w}_{ij}$$
$$G_{ij} = \frac{w_{ij}}{w_{ki}} G_{kj}$$

AND-OR Perceptron



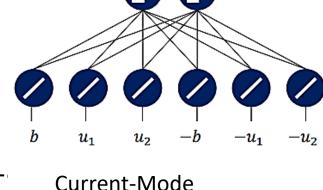
12

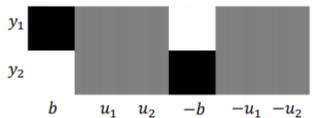
 Simple perceptron trained to perform AND and OR logic functions then mapped to currentmode xbar

Voltage-Mode	Current-Mode	
100% ©	50% 🕾	

Accuracy:

 Current-mode weight matrix has large mismatch from target:





www.rit.edu/brainlab

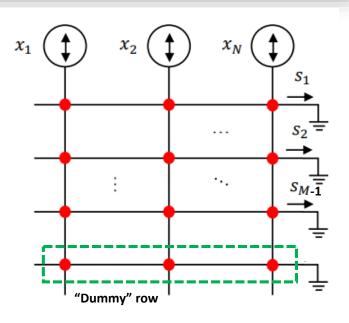
Addition of Dummy Row

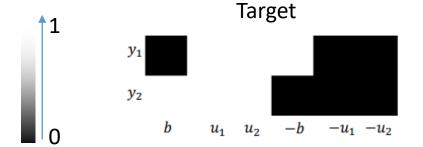


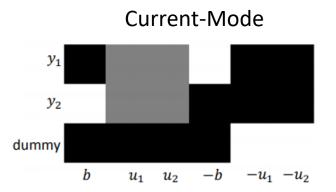
- Dummy row allows magnitude _{x1} of entire column to be adjusted
- Now, set weights as:

$$w_{ij} = \overline{w}_{ij} \ \forall \ i < M$$

$$w_{Mj} = 1 - \sum_{k=1}^{M} \overline{w}_{kj}$$







Restrict Target Weights



 Finally, to make sure a target matrix can be mapped to the current-mode crossbar:

$$\max\left(\frac{1-w_{max}}{M-1},w_{min}\right) \leq \overline{w}_{ij} \leq \min\left(\frac{1-w_{min}}{M-1},w_{max}\right)$$

 The target matrix constraint can be satisfied using regularization techniques

With these constraints, any voltage-mode crossbar maps uniquely to an equivalent current-mode crossbar.

Bipolar Weights



- We can create bipolar (positive and negative) weights without the need for two memristors
- We know the total current from the pre-synaptic neurons
 - Just subtract a fraction of it to get positive and negative weights

$$s_i = \sum_{j=1}^{N} \frac{G_{ij}}{\sum_{k=1}^{N} G_{kj}} x_j - \theta \sum_{j=1}^{N} x_j = w_{ij}^* x_j$$

where $w_{ij}^* = w_{ij} - \theta$

• Good choice for θ is usually $\frac{\overline{w}_{max} + \overline{w}_{min}}{2}$

Gradient Descent

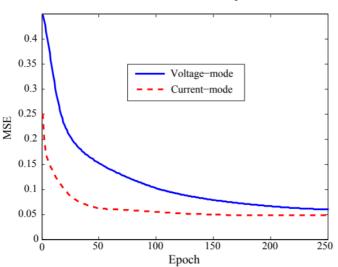


- We can train offline using the proposed method, but online training is more desirable
- Gradient descent can be implemented as

$$\Delta G_{ij}^l = -\alpha \frac{\partial J}{\partial G_{ij}^l} = \alpha \sum_{k=1}^{M^l} \delta_k^l x_j^{l-1} \frac{\partial w_{kj}^l}{\partial G_{ij}^l}$$

$$\approx \begin{cases} \alpha \delta_i^l x_j^l & i \neq M \\ -\langle \Delta G_{1:M-1,j}^l \rangle & i = M \end{cases}$$

AND/OR Perceptron



Just use delta rule for non-dummy rows and average the updates for dummy row



- Background and Motivation
- Current-Mode Crossbars
- MNIST Experiments
- Conclusions and Future Work

MNIST Experiments

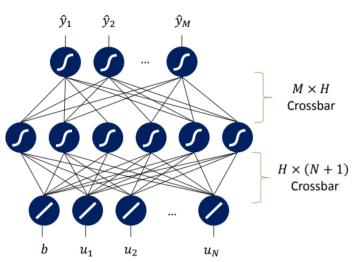


 Circuits modeled in MATLAB based on Ag chalcogenide devices¹:

$$-G_{min} = 2.1 \times 10^{-5} \text{ S}$$

 $-G_{max} = 1 \times 10^{-3} \text{ S}$

 MLP with 49 inputs, 50 hidden units, and 10 outputs



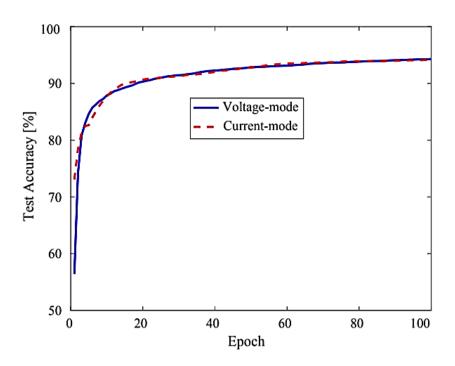
 Classification on MNIST handwritten digits (60000 train, 10000 test)

¹A. S. Oblea et al., "Silver Chalcogenide Based Memristor Devices," Proceedings of the IEEE , vol. 3, 2010.

Classification Accuracy



- Trained using online backpropagation
 - Delta rule for voltage-mode
 - Derived rule for current-mode



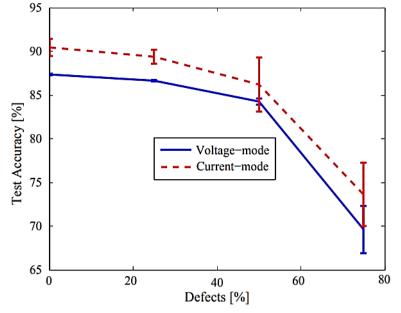
Similar convergence and final accuracy values

Defect Tolerance



 Defects in the current-mode crossbar (e.g. stuckat faults) will affect the weight range of each row

in the colum



- Results indicate that current-mode design may be as robust as voltage-mode
 - More results are needed to verify



- Background and Motivation
- Current-Mode Crossbars
- MNIST Experiments
- Conclusions and Future Work

Conclusions and Future Work



brain·lab

Conclusions:

- Current-mode memristor crossbars may be a viable alternative to voltage-mode designs
 - Similar training convergence and defect tolerance
- Some considerations
 - Reduced weight range
 - Need for a dummy row

Future work

- SPICE simulations for power consumption and performance analysis
- Deeper analysis of weight distributions and feature extraction

Thank You!

